# **74AUP2GU04**

# Low-power dual unbuffered inverter

Rev. 8 — 31 January 2202

**Product data sheet** 

## 1. General description

The 74AUP2GU04 is a dual unbuffered inverter. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- · Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74AUP2GU04GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2						
74AUP2GU04GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886						
74AUP2GU04GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115						
74AUP2GU04GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202						



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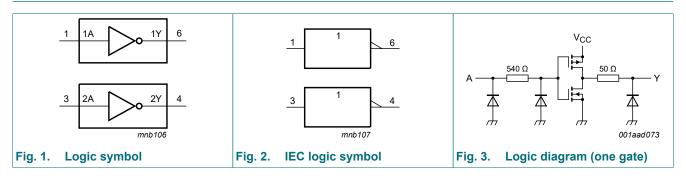
## 4. Marking

#### Table 2. Marking

Type number	Marking code[1]
74AUP2GU04GW	aD
74AUP2GU04GM	aD
74AUP2GU04GN	aD
74AUP2GU04GS	aD

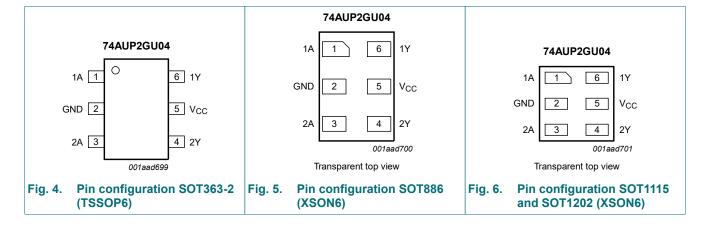
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



# 6. Pinning information

### 6.1. Pinning



**Product data sheet** 

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## 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V <sub>CC</sub>	5	supply voltage
1Y	6	data output

## 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output
nA	nY
L	Н
Н	L

# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Vo	output voltage		[2]	-0.5	V <sub>CC</sub> + 0.5	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[3]	-	250	mW

- [1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.
- [2] The output voltage ratings may be exceeded if the output current ratings are observed.
- [3] For SOT363-2 (TSSOP6) package: P<sub>tot</sub> derates linearly with 3.7 mW/K above 83 °C.
  - For SOT886 (XSON6) package:  $P_{tot}$  derates linearly with 3.3 mW/K above 74 °C.
  - For SOT1115 (XSON6) package:  $P_{tot}$  derates linearly with 3.2 mW/K above 71 °C.
  - For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

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# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		8.0	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage		0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

## 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C				1	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V to 3.6 V	0.75 × V <sub>CC</sub>	-	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.25 × V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = GND or V <sub>CC</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = GND or V <sub>CC</sub>				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	1.5	-	pF
Co	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.8	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V to 3.6 V	0.75 × V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.25 × V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = GND or V <sub>CC</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = GND or V <sub>CC</sub>				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μA
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μA
T <sub>amb</sub> = -	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V to 3.6 V	0.75 × V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.25 × V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = GND or V <sub>CC</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	_	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = GND or V <sub>CC</sub>				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ

# 11. Dynamic characteristics

### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F		·							
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7	2]							
	delay	V <sub>CC</sub> = 0.8 V	-	6.2	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	0.9	2.3	4.4	0.9	4.8	0.9	5.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	0.7	1.7	3.1	0.6	3.4	0.6	3.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.5	1.4	2.6	0.5	2.9	0.5	3.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.4	1.1	2.0	0.4	2.3	0.4	2.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.3	1.0	1.8	0.3	2.1	0.3	2.4	ns
C <sub>L</sub> = 10	pF		'						•	
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7	2]							
	delay	V <sub>CC</sub> = 0.8 V	-	9.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	1.2	3.1	6.1	1.2	6.8	1.2	7.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.0	2.3	4.0	0.9	4.6	0.9	5.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.8	1.9	3.3	0.7	3.8	0.7	4.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.6	1.5	2.7	0.6	3.1	0.6	3.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	1.3	2.4	0.5	2.7	0.5	3.0	ns
C <sub>L</sub> = 15	pF		'		'			<u> </u>	'	_
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7	2]							
	delay	V <sub>CC</sub> = 0.8 V	-	13.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	1.6	3.8	7.9	1.4	8.8	1.4	9.7	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.3	2.8	4.9	1.1	5.7	1.1	6.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.0	2.3	4.0	0.9	4.7	0.9	5.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.8	1.9	3.2	0.8	3.7	0.8	4.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.7	1.6	2.9	0.7	3.3	0.7	3.7	ns

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Symbol	Parameter	Conditions	ons 25 °C		conditions 25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max		
C <sub>L</sub> = 30	pF										
t <sub>pd</sub>	propagation	nA to nY; see Fig. 7 [2]									
	delay	V <sub>CC</sub> = 0.8 V	-	23.2	-	-	-	-	-	ns	
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.4	6.0	13.1	2.2	14.8	2.2	16.3	ns	
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.0	4.2	7.6	1.8	9.0	1.8	9.9	ns	
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.7	3.6	6.1	1.5	7.2	1.5	8.0	ns	
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.9	4.8	1.3	5.7	1.3	6.3	ns	
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.2	2.5	4.3	1.1	5.1	1.1	5.7	ns	
C <sub>L</sub> = 5 p	F, 10 pF, 15 pF	and 30 pF									
C <sub>PD</sub>	power	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3] [4]									
	dissipation capacitance	V <sub>CC</sub> = 0.8 V	-	1.1	-	-	-	-	-	pF	
	сараспапсе	V <sub>CC</sub> = 1.1 V to 1.3 V	-	1.1	-	-	-	-	-	pF	
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	1.3	-	-	-	-	-	pF	
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	1.5	-	-	-	-	-	pF	
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.0	-	-	-	-	-	pF	
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.5	-	-	-	-	-	pF	

- All typical values are measured at nominal V<sub>CC</sub>.
- [2]
- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . All specified values are the average typical values over all stated loads. [3]
- $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

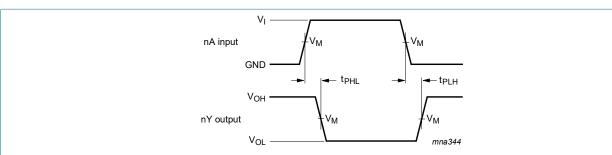
C<sub>L</sub> = load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

## 11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drops that occur with the output load.

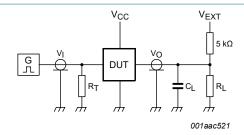
The data input (nA) to output (nY) propagation delays Fig. 7.

Table 9. Measurement points

Supply voltage	Output			
V <sub>CC</sub>	V <sub>M</sub>	VI	t <sub>r</sub> = t <sub>f</sub>	V <sub>M</sub>
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>

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Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

R<sub>T</sub> = Termination resistance should be equal to the output impedance Z<sub>o</sub> of the pulse generator;

V<sub>EXT</sub> = External voltage for measuring switching times.

### Fig. 8. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ . For measuring propagation delays, set-up and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

### 12. Additional characteristics

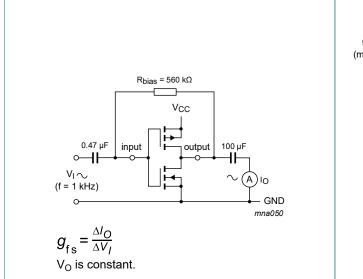
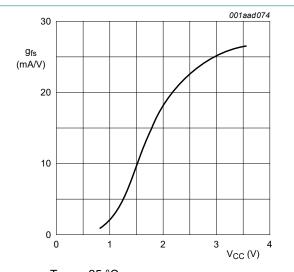


Fig. 9. Test set-up for measuring forward transconductance



 $T_{amb} = 25 \, ^{\circ}C.$ 

Fig. 10. Typical forward transconductance as a function of supply voltage

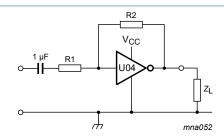
#### Low-power dual unbuffered inverter

## 13. Application information

Some applications for the 74AUP2GU04 are:

- Linear amplifier (see <u>Fig. 11</u>)
- Crystal oscillator (see Fig. 12)

Remark: All values given are typical values unless otherwise specified.



 $Z_L > 10 \text{ k}\Omega$ .

R1 ≥ 3 k $\Omega$ .

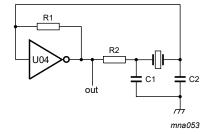
 $R2 \le 1 M\Omega$ .

Open loop amplification:  $A_{OL} = 20$ .

Voltage amplification: 
$$A_V = -\frac{A_{OL}}{1 + \frac{R1}{R2}(1 + A_{OL})}$$

 $V_{o(p-p)} = V_{CC}$  - 1.5 V centered at 0.5 ×  $V_{CC}$ . Unity gain bandwidth product is 5 MHz.

Fig. 11. Linear amplifier application



C1 = 47 pF.

C2 = 22 pF.

R1 = 1 M $\Omega$  to 10 M $\Omega$ .

R2 optimum value depends on the frequency and required stability against changes in  $V_{CC}$  or average minimum  $I_{CC}$  ( $I_{CC}$  = 2 mA at  $V_{CC}$  = 3.3 V and f = 10 MHz).

Fig. 12. Crystal oscillator application

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# 14. Package outline

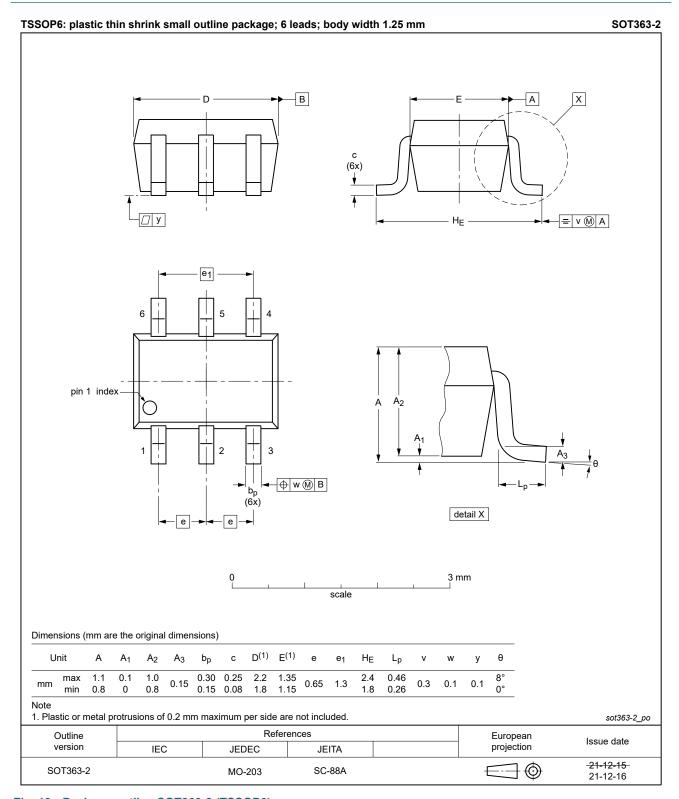


Fig. 13. Package outline SOT363-2 (TSSOP6)

### Low-power dual unbuffered inverter

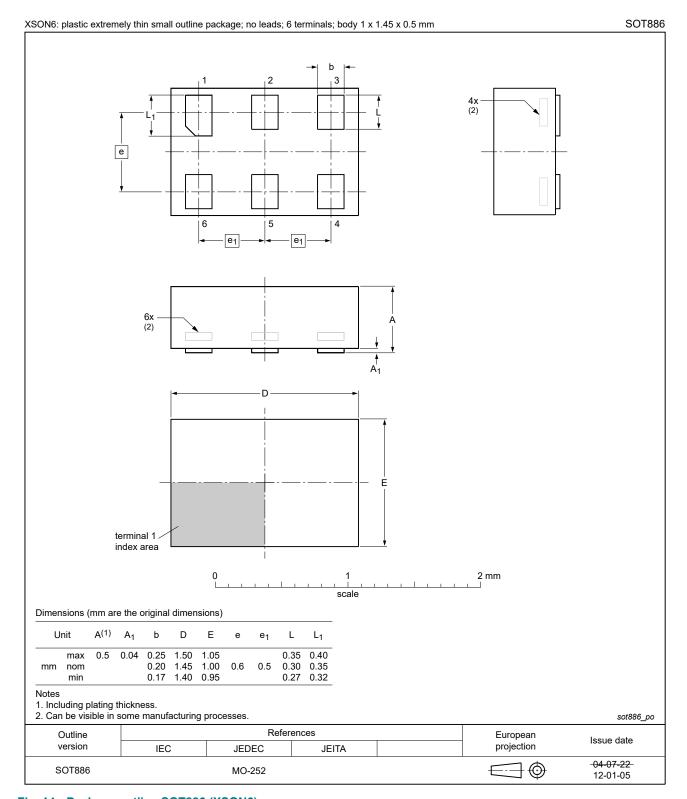


Fig. 14. Package outline SOT886 (XSON6)

### Low-power dual unbuffered inverter

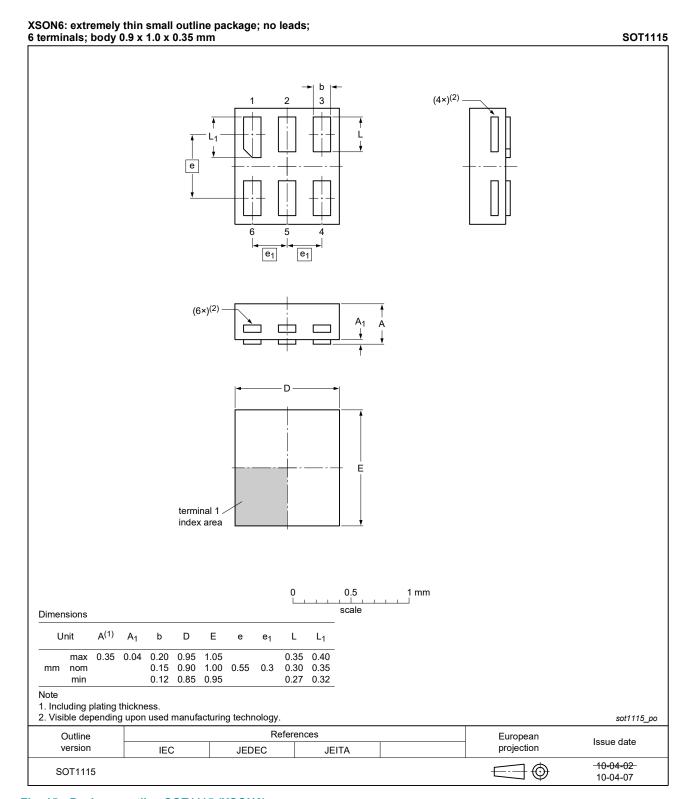


Fig. 15. Package outline SOT1115 (XSON6)

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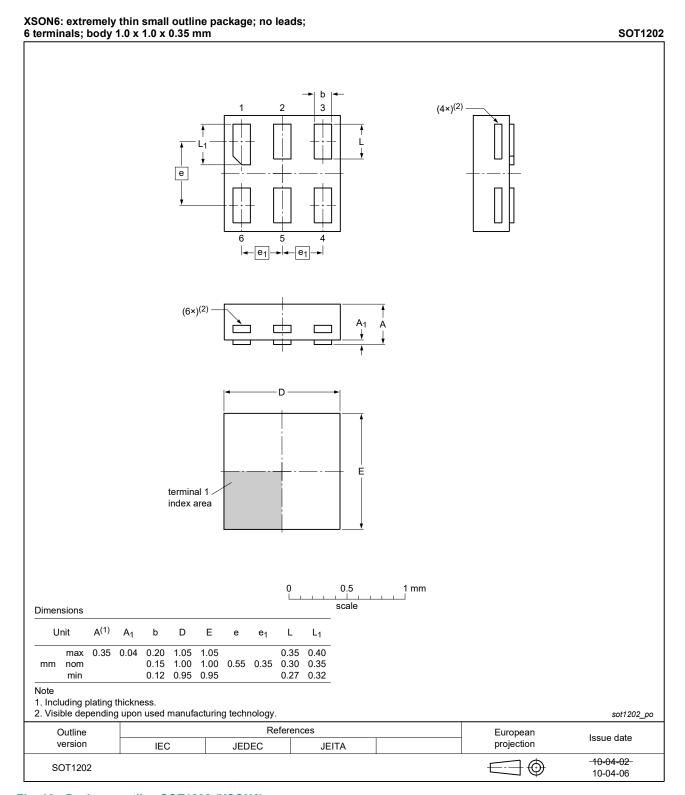


Fig. 16. Package outline SOT1202 (XSON6)

### Low-power dual unbuffered inverter

## 15. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 16. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP2GU04 v.8	20220131	Product data sheet	-	74AUP2GU04 v.7	
Modifications:	• SOT363 (S	C-88) package changed	to SOT363-2 (TSSC	DP6).	
74AUP2GU04 v.7	20210809	Product data sheet	-	74AUP2GU04 v.6	
Modifications:	Section 1 a	<ul> <li>Type number 74AUP2GU04GF (SOT891/XSON6) removed.</li> <li>Section 1 and Section 2 updated.</li> <li>Table 5: Derating values for Ptot total power dissipation updated.</li> </ul>			
74AUP2GU04 v.6	20190128	Product data sheet	-	74AUP2GU04 v.5	
Modifications:	guidelines	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
74AUP2GU04 v.5	20131011	Product data sheet	-	74AUP2GU04 v.4	
Modifications:	Package or	Package outline drawing of SOT886 (Fig. 14) modified.			
74AUP2GU04 v.4	20111207	Product data sheet	-	74AUP2GU04 v.3	
Modifications:	Legal page	Legal pages updated.			
74AUP2GU04 v.3	20101110	Product data sheet	-	74AUP2GU04 v.2	
74AUP2GU04 v.2	20090703	Product data sheet	-	74AUP2GU04 v.1	
74AUP2GU04 v.1	20061215	Product data sheet	-	-	

#### Low-power dual unbuffered inverter

## 17. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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# **74AUP2GU04**

### Low-power dual unbuffered inverter

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